

L Number	Hits	Search Text	DB	Time stamp
124	1440	((dielectric insulat\$3) near (layer film)) with (gap groove opening hole via recess\$2 trench\$2) with (dielectric near constant))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/03/25 16:24

L Number	Hits	Search Text	DB	Time stamp
134	5530	decoupling near capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/25 17:34
137	10877	(ferroelectric perovskite relaxor paraelectric perovskite (dielectric near constant) (Ta."sub.2"O."sub.5") (BaTiO."sub.3") (SrTiO."sub.3") PZT BST BSTO SBT) with (gap via hole opening recess trench\$2 groove)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/25 17:39
138	76	(decoupling near capacitor) and ((ferroelectric perovskite relaxor paraelectric perovskite (dielectric near constant) (Ta."sub.2"O."sub.5") (BaTiO."sub.3") (SrTiO."sub.3") PZT BST BSTO SBT) with (gap via hole opening recess trench\$2 groove))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/25 17:39